## **Tetradentate Schiff base platinum(II) complexes as new class of phosphorescent materials for high-efficiency and white-light electroluminescent devices†**

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The capabilities of readily prepared and sublimable Pt(II) Schiff **base triplet emitters as OLED dopants have been examined; maximum luminous and power efficiencies and luminance of 31** cd  $A^{-1}$ , 14 lm W<sup>-1</sup>, and 23,000 cd m<sup>-2</sup>, respectively, and white **EL (CIE: 0.33, 0.35) by simultaneous host/dopant emission, have been achieved.**

Schiff base ancillary ligands based on the parent *N*,*N*'-bis(salicylidene)-1,2-ethylenediamine (H2salen) have impacted profoundly on a number of research areas for at least the last decade, with enantioselective organic oxidation being a notable example.1 Nevertheless, application studies on metal–salen derivatives in material science remain sparse in the literature.2,3 Hamada and coworkers pioneered the development of zinc(II) complexes bearing Schiff base ligands as blue to greenish-white emitters for employment in organic optoelectronics.4 We now demonstrate that platinum(II) Schiff base compounds constitute an attractive class of phosphorescent materials that are easily synthesized, thermally stable, structurally diverse, and potentially important in materials applications.

Treatment of  $K_2PtCl_4$  with the respective Schiff base in an aqueous KOH solution (1 M) under an argon atmosphere,5 followed by appropriate purification steps, gave [Pt(L*1–3*)] (**1–3**,  $H_2L^1$  =  $N$ , $N'$ -bis(salicylidene)-1,2-ethylenediamine;  $H_2L^2$  =  $N$ , $N'$ -bis(salicylidene)-1,3-propanediamine;  $H_2L^3 = N$ , $N'$ -bis(salicylidene)-1,1,2,2-tetramethylethylenediamine) as orange crystalline solids. Complexes **1–3** are stable in air, and no decomposition or ligand dissociation was observed in ethanol, 2-propanol, DMSO or acetonitrile under ambient conditions after several days. Thermogravimetric analysis (TGA) showed that all three complexes are stable under a nitrogen atmosphere up to 360 °C, and the decomposition temperatures of **1–3** are 406, 369 and 382 °C respectively.† In addition, **3** was observed to sublime before its decomposition temperature was reached, hence slow weight loss was detected from around 200 °C (to 95 wt%) before decomposition occurred.

The molecular structure of **3** was determined by X-ray crystallography‡ and is depicted in Fig. 1. In contrast to the



The absorption spectra of **1–3** in acetonitrile feature two intense absorption bands at around 340 ( $\varepsilon \approx 1 \times 10^4$  mol<sup>-1</sup> dm<sup>3</sup> cm<sup>-1</sup>) and  $420$  ( $\varepsilon \approx 0.5 \times 10^4$  mol<sup>-1</sup> dm<sup>3</sup> cm<sup>-1</sup>) nm, plus a weak low-energy absorption shoulder at around 500 nm ( $\varepsilon \approx 60-80$  mol<sup>-1</sup> dm<sup>3</sup>  $cm^{-1}$ ; see Fig. 2 for **3**). Solvatochromic studies on **3** showed that the low-energy absorptions ( $\lambda > 400$  nm) undergo red shifts in low-polarity solvents (*e.g.* broad absorption at  $\lambda_{\text{max}}$  411 nm in MeOH becomes two distinct bands at  $\lambda_{\text{max}}$  433 and 455 nm in  $C_6H_6$ ). We tentatively assign this absorption to a charge transfer transition involving the phenoxide lone pair (1) and the  $\pi^*$  orbital of imine, *i.e.* <sup>1</sup>[l(phenoxide)  $\rightarrow \pi^*$ (imine)], mixed with <sup>1</sup>[Pt(5d)  $\rightarrow$  $\pi^*$ (Schiff base)] MLCT character.

Complexes **1–3** exhibit intense phosphorescence in fluid solutions ( $\lambda_{\text{max}}$  537–592 nm; see Fig. 2 for **3** in acetonitrile) and in the solid state ( $\lambda_{\text{max}}$  548–598 nm) at room temperature (Table S1†). In acetonitrile at 298 K, **1**, **2** and **3** emit ( $\tau/\mu$ s;  $\Phi_{\text{em}}$ ) at  $\lambda_{\text{max}}$  550 (3.5; 0.19), 592 (0.5; 0.09) and 541 (3.4; 0.18) nm, respectively. Compared to the absorption data, the emission of **3** displays smaller solvatochromic effects (*e.g.*  $\lambda_{\text{max}}$  in MeOH at 537 nm is red-shifted by only *ca*. 300 cm<sup>-1</sup> to 546 nm in  $C_6H_6$ ). The triplet emissive excited state of **3** in degassed acetonitrile is characterized by an absorption band at *ca*. 480 nm,† and the measured decay lifetime of  $3.6 \,\mu s$  closely matches the emission lifetime in acetonitrile (3.4  $\mu s$ ). Complex **1** exhibits an irreversible anodic wave at 0.54 V *vs*.  $Cp<sub>2</sub>Fe<sup>+/0</sup>$  in DMF. Based on the electrochemical data, the excited state of **1** is a powerful reductant with  $E^{\circ}(1^{+}/1^{*}) \le -1.6$  V *vs*. SSCE. A comparable value of  $-1.75$  V *vs*. SSCE was derived from quenching studies with pyridinium acceptors.†

The sublimability, relatively short emission lifetimes (*cf*. > 50 us for PtOEP7) and high photoluminescent quantum efficiencies of complexes **1** and **3** render them suitable candidates as efficient electrophosphorescent dopants. OLEDs with emitting layers comprising the host material 4,4'-(*N,N'*-dicarbazole)biphenyl (CBP) plus **3** as dopant at different concentrations were fabricated







**Fig. 2** Absorption (dot), excitation (dash,  $\lambda_{em} = 541$  nm) and emission (solid line,  $\lambda_{\text{ex}} = 413 \text{ nm}$ ) spectra of **3** in acetonitrile at 298 K.

(configuration: [ITO/NPB (400 Å)/CBP:**3** (300 Å)/BCP (200 Å)/ Alg<sub>3</sub> (300 Å)/LiF (5 Å)/Al (1500 Å)]).<sup>†</sup> These devices require low turn-on voltages of around 3 V. At 1.0 to 6.0 wt%, only EL from the dopant **3** at  $\lambda_{\text{max}}$  550 (sh 590) nm is observed, although a minor peak at  $\lambda_{\text{max}}$  420 nm from NPB is visible at 0.5 wt%.

At the optimized dopant concentration of 4.0 wt%, the maximum external quantum efficiency ( $\eta_{ext}$ ), luminous efficiency ( $\eta_L$ ), power efficiency ( $\eta_P$ ), and luminance are (current density/mA cm<sup>-2</sup> in parentheses): 11% (8.5), 31 cd A<sup>-1</sup> (8.5), 14 lm W<sup>-1</sup> (8.5), and 23,000 cd m<sup> $-2$ </sup> (683), respectively (Fig. 3). The performance of the **3**-doped OLED (4.0 wt%) at different current density is listed in Table 1. We note that (i) even at the high luminance of 10,000 cd  $m^{-2}$ ,  $\eta_{ext}$ ,  $\eta_L$ , and  $\eta_P$  is 4.1%, 13 cd A<sup>-1</sup>, and 4.0 lm W<sup>-1</sup>, respectively, and (ii) reasonable  $\eta_L$  is observed at very high current densities (*e.g.* 4.1 cd  $A^{-1}$  at 500 mA cm<sup>-2</sup>). The EL spectra for this OLED exhibit no significant change from 3 to 16 V, and the Commission Internationale de l'Eclairage (CIE) coordinates at 8 V are (0.48, 0.52), which correspond to orange light.

In order to realise the generation of white EL, devices comprising the host material  $bis(2(2'-hydroxyphenyl)pyridine)$ beryllium (Bepp2) plus complex **1** as dopant at different concentrations were prepared (configuration:  $[ITO/NPB (500 Å)/Bepp<sub>2</sub>:1 (500 Å)/LiF]$  $(15 \text{ Å})$  /Al  $(1500 \text{ Å})$ , with devices A–D corresponding to 3.2, 7.7, 11.1 and 16.7 wt% of **1** respectively; Fig. 4).† All devices begin to glow at 4–5 V and exhibit two emission bands at  $\lambda_{\text{max}}$  448 and 552 nm in the EL spectra. Device A (3.2 wt% of **1**) gives a luminous efficiency of 0.79 lm  $W^{-1}$  and luminance of 450 cd m<sup>-2</sup> at 20 mA cm<sup>-1</sup>. The highest achieved luminance is 3045 cd m<sup>-2</sup> at 307 mA  $cm<sup>-2</sup>$ . Importantly, the CIE coordinates of device A are  $(0.33,$ 0.35), which closely approaches that of white light (defined as 0.33, 0.33); the white emission is produced by the simultaneous EL of Bepp2 and **1** in the device. Upon increasing the concentration of **1**, both the luminance and luminous efficiency are enhanced and the emission of **1** becomes more dominant in the EL spectra (especially in device C). However, the overall device efficiency diminishes at 16.7 wt% (device D); this is consistent with aggregation of dopant molecules at sufficiently high concentrations, which can lead to intermolecular quenching.

Saliently, the performance of OLEDs employing the Schiff base dopant **3** are substantially superior to previously reported results for platinum( $\pi$ ) emitters,<sup>7,8</sup> and the excellent brightness and efficiencies approach or are comparable to those obtained for the



**Fig. 3** Current density and luminance curves of **3**-doped OLED (4.0 wt %) against applied voltage.

**Table 1** Performance of **3**-doped OLED (4.0 wt %) at different *Ia*

Current density/ $mA \text{ cm}^{-2}$	V/V	$cd~m^{-2}$	$\eta_{\rm ext}$ (%)	$\eta_{\rm L}$ $cd A^{-1}$	$\eta_{\rm P}$ / $\rm{Im} W^{-1}$
	4.0	14	0.47	1.4	1.1
10	7.1	3 0 1 0	11	30	13
20	8.1	5 0 5 0	9.1	25	10
100	10.0	11 500	3.9	11	3.5
500	14.5	21 200	1.5	4.1	0.9
		a Configuration: [ITO/NPB/CBP:3/BCP/Alq <sub>3</sub> /LiF/Al].			



**Fig. 4** EL spectra of devices A–D (3.2, 7.7, 11.1 and 16.7 wt% of **1** respectively) and corresponding CIE coordinates (inset, cross indicates pure white emission).

intensely studied bis- and tris-cyclometalated iridium(III) electrophosphorescent materials.9 While most examples of white OLEDs require multilayer configurations,8b,10 we note that pure white EL has been achieved in this work using a relatively simple device configuration.

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## **Notes and references**

 $\ddagger$  Crystal data for **3**: C<sub>20</sub>H<sub>22</sub>N<sub>2</sub>O<sub>2</sub>Pt, *M* = 517.49, monoclinic, *P*2<sub>1</sub>/*c*, *a* = 22.384(5),  $b = 20.718(4)$ ,  $c = 12.077(2)$  Å,  $\beta = 94.90(3)$ °,  $V = 5580(2)$ Å<sup>3</sup>, *T* = 253(2) K, *Z* = 12,  $\mu$  = 7.558 mm<sup>-1</sup>,  $2\theta_{\text{max}}$  = 50.7°, 9009 independent reflections ( $R_{\text{int}} = 0.069$ ), 658 parameters,  $R_1 = 0.039$  ( $I >$  $2\sigma(I)$ ),  $wR_2 = 0.081$ . CCDC 217004. See http://www.rsc.org/suppdata/cc/ b4/b402318h/ for crystallographic data in .cif or other electronic format.

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